

L Number	Hits	Search Text	DB	Time stamp
1	5082	(gate near insulating near film) near5 (thin\$3 or thick\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/07 14:20
3	1331	((gate near insulating near film) near5 (thin\$3 or thick\$6)) and (contact near hole) and (gate near electrode)	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/07 14:24
4	6	((gate near insulating near film) near5 (thin\$3 or thick\$6)) and (contact near hole) and (gate near electrode)) and wir\$3 and (first near diffus\$5 near layer) and (second near diffus\$5 near layer)	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/07 14:27